NSN 5961-01-122-6714

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View Online at https://aerobasegroup.com/nsn/5961-01-122-6714 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Overall Diameter:** 0.830 inches **End Application:** 5865-01-096-4994 **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-204 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 drain to source voltage **Current Rating Per Characteristic:** 24.00 amperes drain current and 60.00 amperes off-state current, peak **Power Rating Per Characteristic:** 150.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 1 case and 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: